



Ruttonsha International Rectifier Ltd.

SILICON RECTIFIERS

TYPE: R 2800M..F SERIES

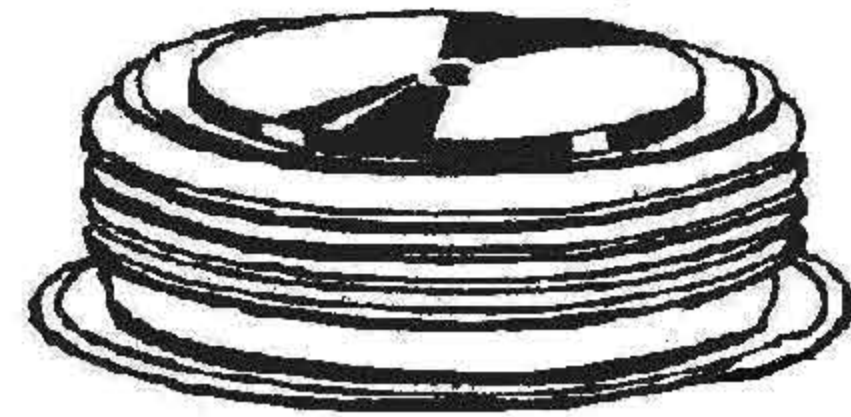
FAST RECOVERY DIODES

Typical Applications

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications

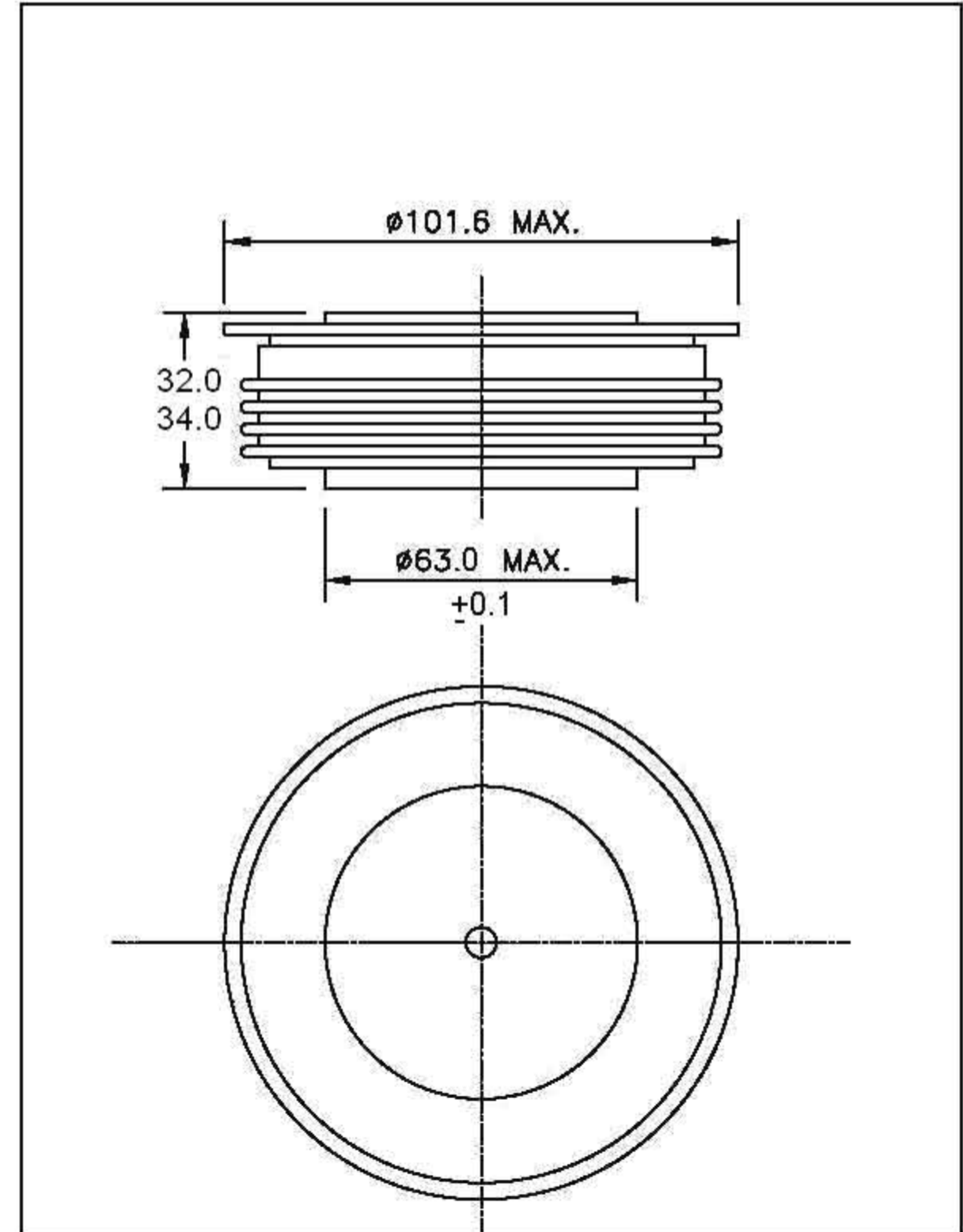
Hockey Puk Version

CASE STYLE (M-PUK)



Major Ratings and Characteristics

| Parameters | R2800M..F | Units |
|------------------|--------------|-------|
| $I_{F(AV)}$ | 2837 | A |
| $@ T_{hs}$ | 55 | °C |
| $I_{F(RMS)}$ | 4454 | A |
| $I_{FSM} @ 50Hz$ | 35000 | A |
| V_{RRM} range | 1800 to 2500 | V |
| $t_{tr} @ T_J$ | 7.0 | μs |
| | 150 | °C |
| T_J | - 40 to 150 | °C |



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ELECTRICAL SPECIFICATIONS

Voltage Ratings

| Type number | Voltage Code | V_{RRM} , maximum repetitive peak reverse voltage V | V_{RSM} , maximum non-repetitive peak rev. voltage V | I_{RRM} max. @ $T_J = T_J$ max. mA |
|------------------|--------------|--|---|--|
| R2800M..F | 18 | 1800 | 1900 | 100 |
| | 22 | 2200 | 2300 | |
| | 25 | 2500 | 2600 | |

Forward Conduction

| Parameter | R2800M..F | Units | Conditions |
|---|------------|----------------------------|---|
| $I_{F(AV)}$ Max. average forward current @ heatsink temperature | 2837 55 | A °C | 180° conduction, half sine wave Double side cooled |
| $I_{F(RMS)}$ Max. RMS forward current | 4554 | A | @ 55°C heatsink temperature double side cooled |
| I_{FSM} Max. peak, one-cycle forward, non-repetitive surge current | 35000 | A | t = 10ms Sinusoidal half wave, Initial $T_J = T_J$ max. |
| I^2t Maximum I^2t for fusing | 6125 | KA ² s | t = 10ms |
| $I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing | 61250 | KA ² \sqrt{s} | t = 0.1 to 10ms, no voltage reapplied |
| $V_{F(TO)}$ Threshold voltage | 0.9 | V | $T_J = T_J$ max. |
| r_T Forward slope resistance | 0.17 | m Ω | $T_J = T_J$ max. |
| V_{FM} Max. forward voltage drop | 1.41 | V | $I_{pk}=3000A$, $T_J = T_J$ max, $t_p = 10ms$ sinusoidal wave |
| t_{rr} Reverse Recovery time | 7.0 | us | IFM=1000A, di/dt=60A/us |

SILICON RECTIFIERS

R2800M..F Series

Thermal and Mechanical Specifications

| Parameter | R2800M..F | Units | Conditions |
|--|------------|-------|---------------------------------|
| T _J Max. junction operating temperature range | -40 to 150 | °C | |
| T _{stg} Max. storage temperature range | -40 to 150 | | |
| R _{thJ-hs} Max. thermal resistance, case junction to heatsink | 0.016 | K/W | DC operation double side cooled |
| F Mounting force, ± 10% | 40 | KN | |
| wt Approximate weight | 1000 | g | |
| Case style | (M-PUK) | | See Outline Table |

Ordering Information Table

| Device Code | | | | | | | | | | | | | |
|-------------|---|----------|-------------|----------|-----------|----------|----------|---|---|---|---|---|---|
| | <table border="1" style="margin: auto;"> <tr> <td style="padding: 5px;">R</td> <td style="padding: 5px;">2800</td> <td style="padding: 5px;">M</td> <td style="padding: 5px;">25</td> <td style="padding: 5px;">C</td> <td style="padding: 5px;">F</td> </tr> <tr> <td style="text-align: center;">①</td> <td style="text-align: center;">②</td> <td style="text-align: center;">③</td> <td style="text-align: center;">④</td> <td style="text-align: center;">⑤</td> <td style="text-align: center;">⑥</td> </tr> </table> | R | 2800 | M | 25 | C | F | ① | ② | ③ | ④ | ⑤ | ⑥ |
| R | 2800 | M | 25 | C | F | | | | | | | | |
| ① | ② | ③ | ④ | ⑤ | ⑥ | | | | | | | | |
| 1 | - R = Diode | | | | | | | | | | | | |
| 2 | - Essential part number | | | | | | | | | | | | |
| 3 | - M = Puk Case | | | | | | | | | | | | |
| 4 | - Voltage code: Code x 100 = V _{RRM} (See Voltage Ratings table) | | | | | | | | | | | | |
| 5 | - C = Ceramic Puk | | | | | | | | | | | | |
| 6 | - F = Fast recovery | | | | | | | | | | | | |